

Transistors

-200mA / -30V Low $V_{CE(sat)}$ Digital transistors (with built-in resistors)

DTB743ZE / DTB743ZM

●Applications

Inverter, Interface, Driver

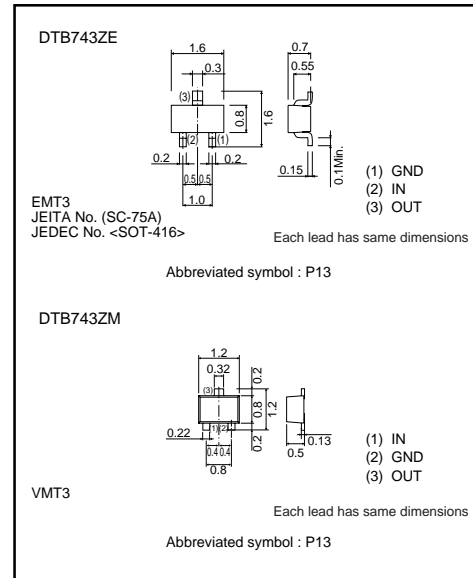
●Feature

- 1) $V_{CE(sat)}$ is lower than conventional products.
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 4) Only the on / off conditions need to be set for operation, making the device design easy.

●Structure

PNP epitaxial planar silicon transistor
(Resistor built-in type)

●External dimensions (Unit : mm)



●Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limits		Unit
		DTB743ZE	DTB743ZM	
Supply voltage	V_{CC}	-30		V
Input voltage	V_{IN}	-20 to +5		V
Collector current *1	$I_C (max)$	-200		mA
Power dissipation *2	P_D	150		mW
Junction temperature	T_J	150		$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150		$^\circ\text{C}$

*1 Characteristics of built-in transistor.

*2 Each terminal mounted on a recommended land.

●Packaging specifications

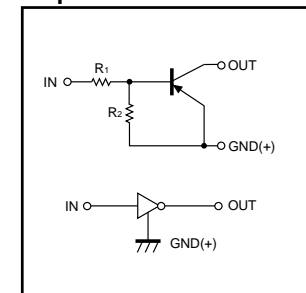
Part No.	Package	EMT3	VMT3
		Packaging type	Taping
	Code	TL	T2L
	Basic ordering unit (pieces)	3000	8000
DTB743ZE		○	—
DTB743ZM		—	○

●Electrical characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	-0.3	V	$V_{CC} = -5V, I_{O} = -100\mu\text{A}$
	$V_{I(on)}$	-2.5	—	—		$V_O = -0.3V, I_{O} = -20\text{mA}$
Output voltage	$V_{O(on)}$	—	-70	-300	mV	$I_O/I_I = -50\text{mA} / -2.5\text{mA}$
Input current	I_I	—	—	-1.4	mA	$V_I = -5V$
Output current	$I_{O(off)}$	—	—	-0.5	μA	$V_{CC} = -30V, V_I = 0V$
DC current gain	G_I	140	—	—	—	$V_O = -2V, I_O = -100\text{mA}$
Transition frequency *	f_T	—	260	—	MHz	$V_{CE} = -10V, I_E = 5\text{mA}, f = 100\text{MHz}$
Input resistance	R_1	3.29	4.7	6.11	k Ω	—
Resistance ratio	R_2/R_1	8.0	10	12	—	—

* Characteristics of built-in transistor.

●Equivalent circuit



$R_1 = 4.7\text{k}\Omega / R_2 = 47\text{k}\Omega$

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